TOSHIBA Transistor Silicon PNP Epitaxial Planar Type

2SA1245

High Frequency Amplifier and Switching Applications VHF~UHF Band Low Noise Amplifier Applications

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-15	V
Collector-emitter voltage	V _{CEO}	-8	V
Emitter-base voltage	V _{EBO}	-2	V
Collector current	IC	-30	mA
Base current	Ι _Β	-15	mA
Collector power dissipation	P _C	150	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	<i>–</i> 55∼125	°C

Weight: 0.012 g (typ.)

Microwave Characteristics (Ta = 25°C)

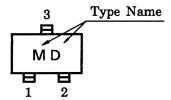
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f _T	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	_	4	_	GHz
Insertion gain	S _{21e} ² (1)	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}, f = 500 \text{ MHz}$	_	14	_	dB
	S _{21e} ² (2)	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}, f = 1 \text{ GHz}$	_	9.5	_	
Noise figure	NF (1)	$V_{CE} = -5 \text{ V}, I_{C} = -3 \text{ mA}, f = 500 \text{ MHz}$	_	2.5	_	dB
	NF (2)	$V_{CE} = -5 \text{ V}, I_{C} = -3 \text{ mA}, f = 1 \text{ GHz}$	_	3.0	_	

Electrical Characteristics (Ta = 25°C)

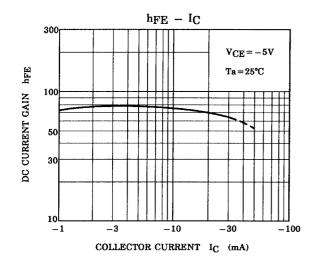
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -5 \text{ V}, I_{E} = 0$	_	_	-0.1	μА
Emitter cut-off current	I _{EBO}	$V_{EB} = -1 \text{ V, } I_{C} = 0$	_	_	-0.1	μА
DC current gain	h _{FE}	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	20	_	_	
Output capacitance	C _{ob}	$V_{CB} = -5 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ (Note)	_	0.75	_	pF
Reverse transfer capacitance	C _{re}		_	0.60	_	pF

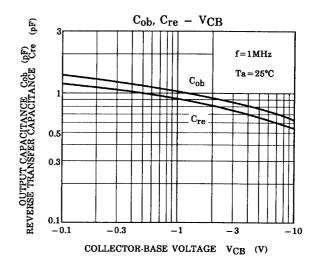
Note: C_{re} is measured by 3 terminal method with capacitance bridge.

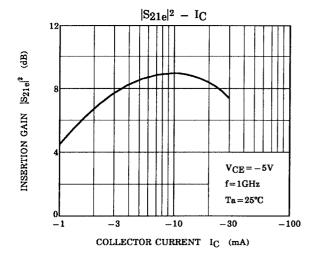
Marking

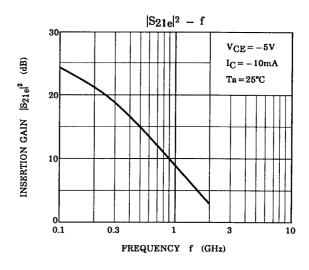


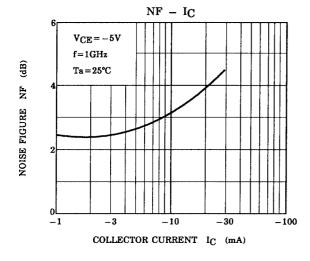
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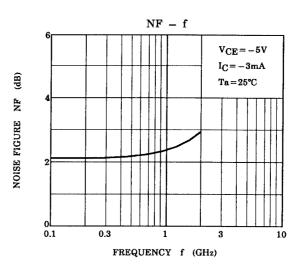








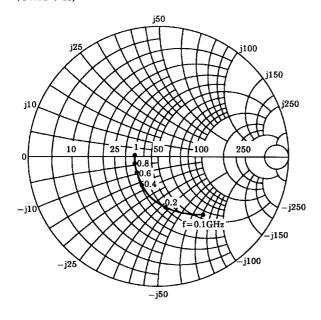


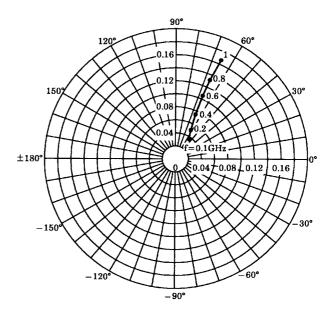


 $\begin{array}{l} S_{11e} \\ V_{CE} = -5V \\ I_{C} = -10 \text{mA} \\ T_{a} = 25 ^{\circ}\text{C} \\ (U\text{NIT}: \Omega) \end{array}$

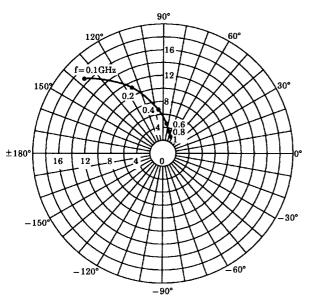


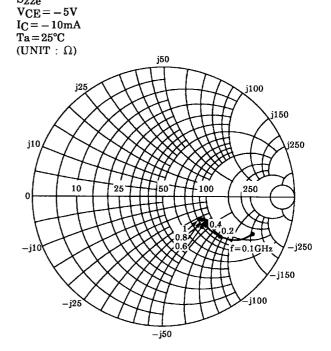
 S_{22e}





 S_{21e} $V_{CE} = -5V$ $I_{C} = -10\text{mA}$ $T_{a} = 25^{\circ}\text{C}$





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